

## Uttarakhand First Nanofabrication Facility | Uttarakhand | 13 Mar 2025

## Why in News?

<u>IIT-Roorkee</u> has established a **cutting-edge** <u>nanofabrication</u> facility in Uttarakhand to advance <u>India's semiconductor manufacturing mission.</u>

## **Key Points**

- International Collaboration:
  - IIT-Roorkee collaborated with Taiwan's premier semiconductor institutions to exchange expertise.
  - The Department of Science and Technology (DST) funded the project, which began in 2019.
- State-of-the-Art Infrastructure:
  - The facility features cutting-edge instruments, including:
    - 50 kV Electron Beam Lithography (EBL) system with 10nm resolution.
    - Inductively Coupled Plasma RIE (ICP-RIE), a key etching technology for semiconductor manufacturing.
  - Equipped with ultra-clean rooms featuring controlled environments:
    - Class 100 space (300 sq ft) and Class 1000 space (600 sq ft) for precision research.
- Research Applications:
  - The facility supports cutting-edge research in:
    - Quantum sensors
    - Spintronics
    - Memory devices
    - Thin-film devices
    - Photodetectors
    - Quantum optics
    - Photonic crystals

## **Department of Science and Technology**

- The foundation of DST was laid on 3rd May 1971 along the model of National Science Foundation (NSF), USA.
- It provides funding and also makes policies and co-ordinates scientific work with other countries.
- It **empowers scientists and scientific institutions** and also works with a highly distributed system permeating stakeholders ranging from school college, PhD, Postdoc students, young scientists, startups and NGOs working in Science & Technology.
- DST's budget has increased over the years by 100%, which has allowed initiation of new programmes in a wide range of areas.



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